

Supplementary Information

Bilayer hexagonal structure MnN₂ nanosheet with room-temperature ferromagnetic half-metal behavior and tunable electronic structure

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Table S1. Elastic constants of BHS-MnN₂, BHS-MnP₂ and BHS-MnAs₂.

	Elastic Constants (N/m)					Young's Modulus (N/m)	Shear Modulus (N/m)	Poisson's Ratio
	C_{11}	C_{22}	C_{12}	C_{66}	$C_{11}- C_{12} $	x or y		x or y
MnN₂	190.28	190.28	64.37	62.96	>0	168.51	62.96	0.34
MnP₂	102.62	102.62	31.16	35.73	>0	93.15	35.73	0.30
MnAs₂	87.21	87.21	17.82	34.69	>0	83.56	34.69	0.20

Table S2. Energy difference between antiferromagnetic and ferromagnetic states of MnN₂, MnP₂ and MnAs₂.

System	$\Delta E_{\text{FM}}(\text{eV})$	$\Delta E_{\text{AFM1}}(\text{eV})$	$\Delta E_{\text{AFM2}}(\text{eV})$	$\Delta E_{\text{AFM3}}(\text{eV})$	$\Delta E_{\text{AFM4}}(\text{eV})$	$\Delta E_{\text{AFM5}}(\text{eV})$
MnN ₂	0	8.12	6.71	4.68	6.24	6.34
MnP ₂	0	3.65	3.30	2.07	2.91	2.58
MnAs ₂	0	6.13	4.48	2.62	4.47	4.07

Table S3. Localized magnetic moment (M , μ_B), exchange parameters J_1 and J_2 , magnetic anisotropic energy and calculated Curie temperature of BHS-MnN₂, BHS-MnP₂ and BHS-MnAs₂.

Substance	$M_{\text{Mn}}(\mu_B)$	$M_{\text{N, P, As}}(\mu_B)$	$M_{\text{Tot}}(\mu_B)$	$J_1(\text{eV})$	$J_2(\text{eV})$	$E_{\text{MAE}}(\mu\text{eV})$	$T_C(\text{K})$
BHS-MnN ₂	2.43	-0.55	5.23	0.169	0.419	3.67	563
BHS-MnP ₂	2.84	-0.38	8.28	0.076	0.206	8.27	705
BHS-MnAs ₂	3.37	-0.42	10.19	0.088	0.194	41.58	1122

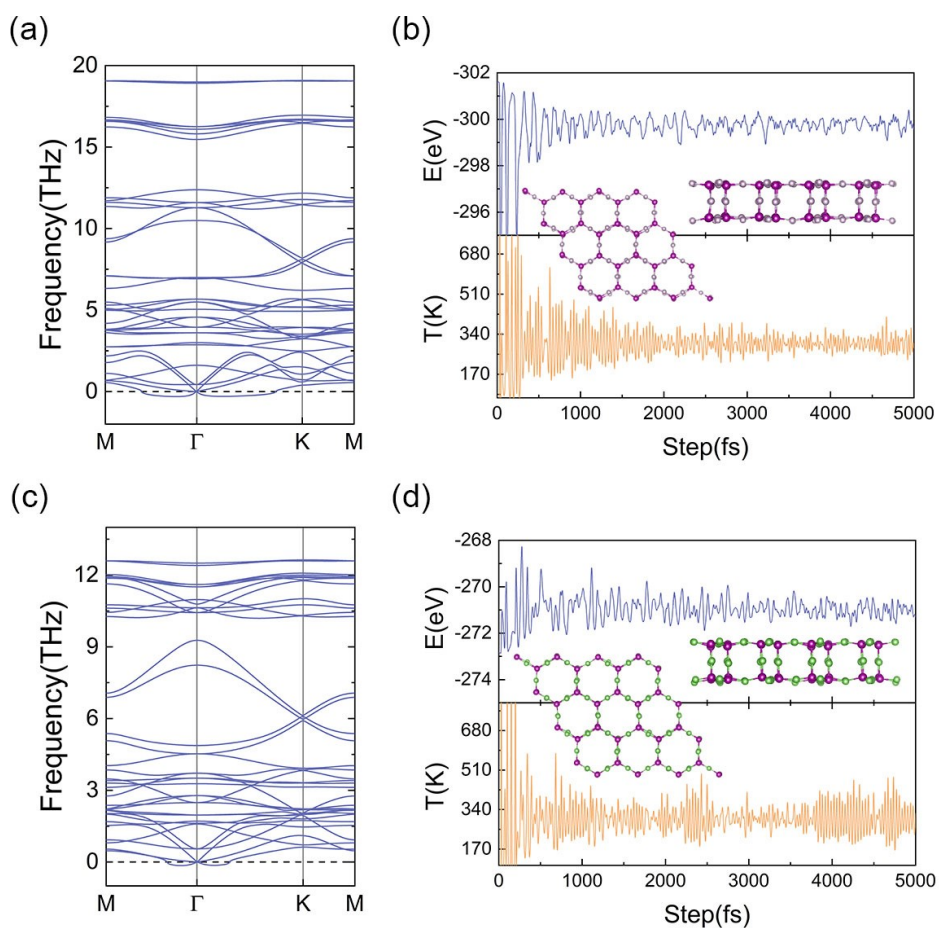


Fig. S1 (a) Phonon dispersions of MnP₂ nanosheet, (b) The fluctuations of energy and temperature as well as the final configuration of MnP₂ are obtained from AIMD simulation, (c) Phonon dispersions of MnAs₂ nanosheet, (d) The fluctuations of energy and temperature as well as the final configuration of MnAs₂ are obtained from AIMD simulation.

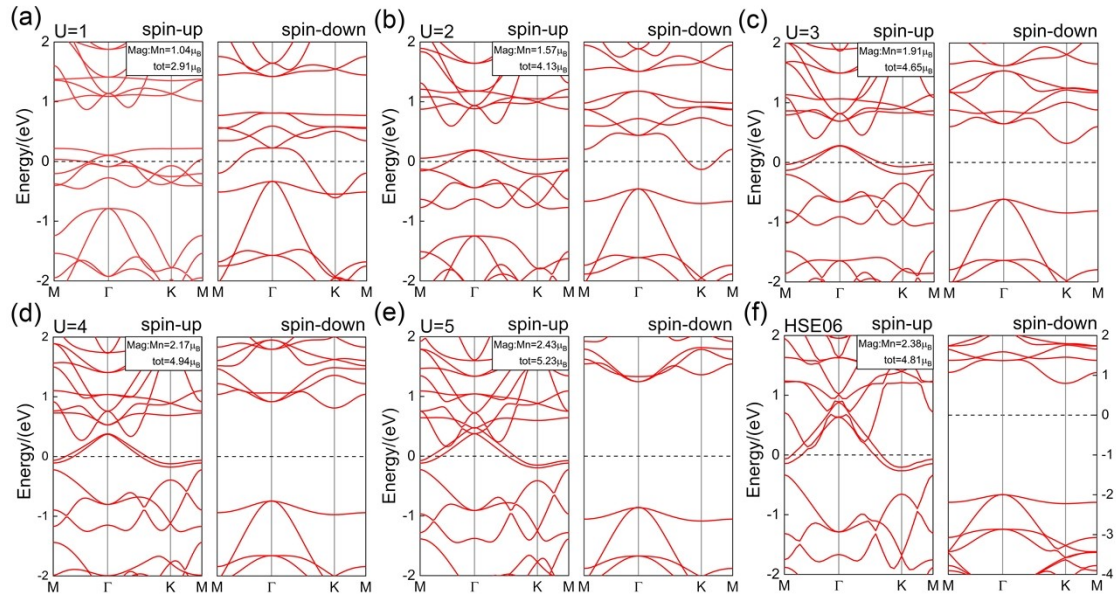


Fig. S2 (a)-(e) Band structures of BHS-MnN₂ nanosheet calculated by PBE+U (U_{eff}=1, 2, 3, 4, 5), and (f) Band structure of BHS-MnN₂ calculated by HSE method.

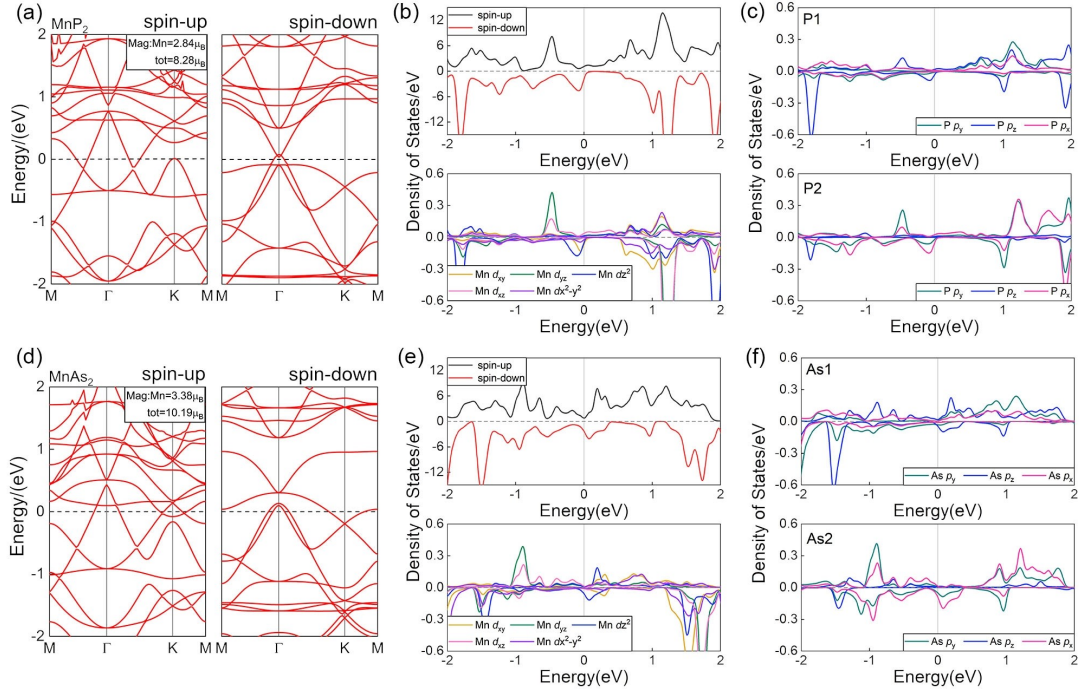


Fig. S3 (a) BHS-MnP₂ spin polarization band structure. (b) Calculate the total DOS of BHS-MnP₂ and the *d*-orbital projection DOS of Mn with $U_{\text{eff}}=5$ eV. (c) *p*-orbital projection DOS for different coordination P. (d) BHS-MnAs₂ polarization band structure. (e) Calculate total DOS for BHS-MnAs₂ and *d*-orbital projection DOS for Mn with $U_{\text{eff}}=5$ eV. (f) *p*-orbital projection DOS for different coordination As.

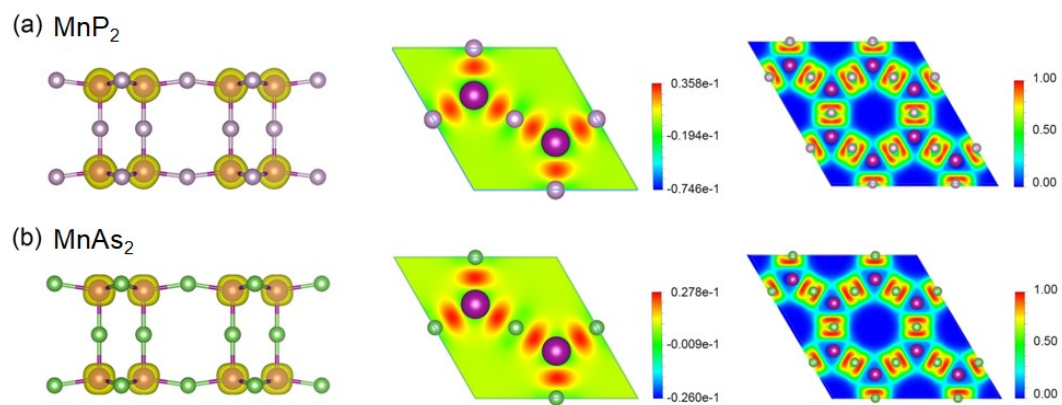


Fig. S4 (a) The spin density distribution, deformed charge density and ELF of BHS-MnP₂. (b) The spin density distribution, deformed charge density and ELF of BHS-MnAs₂.

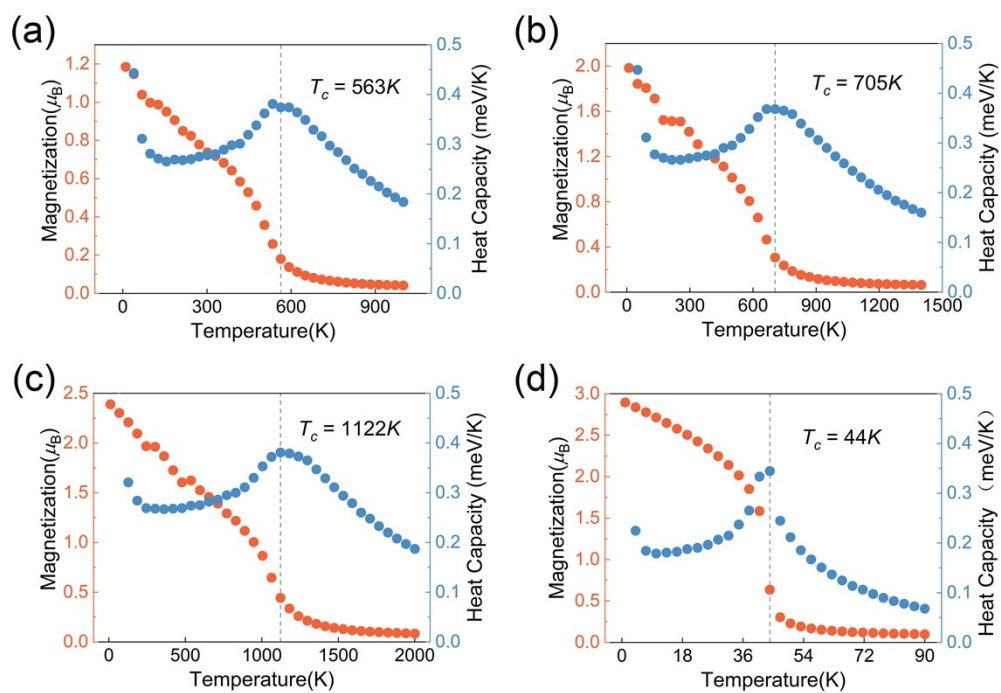


Fig. S5 Magnetic moment per unit cell (red) and specific heat (C_v) (blue) of (a) BHS-MnN₂, (b) BHS-MnP₂, (c) BHS-MnAs₂, (d) CrI₃.

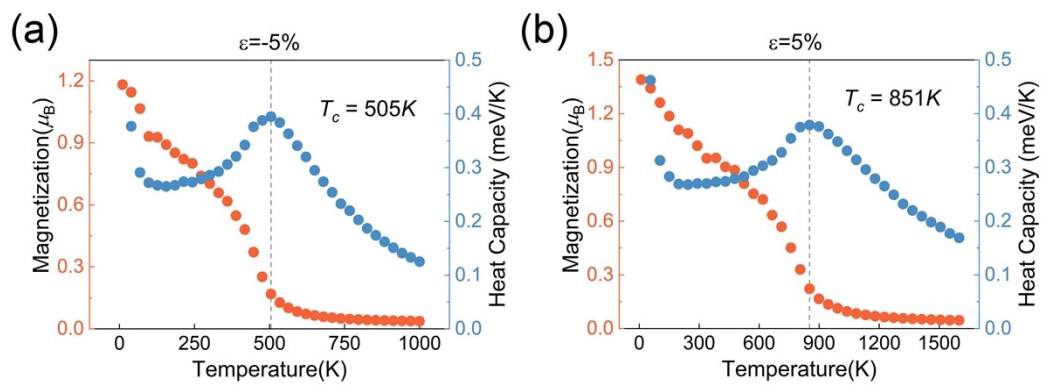


Fig. S6 Variations of magnetic moment and heat capacity of MnN₂ with temperature under (a) 5% and (b) -5% strain.